A nom alous Spectral weight in photoem ission spectra of the hole doped H aldane chain $Y_2 \times Sr_x B$ aN iO₅.

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In this paper, we present photoem ission experiments on the hole doped Haldane chain compound $Y_2 \,_x Sr_x B$ aN iO₅. By using the photon energy dependence of the photoem ission cross section, we identie d the symmetry of the rst ionisation states (d type). Hole doping in this system leads to a significant increase in the spectral weight at the top of the valence band without any change in the vicinity of the Fermi energy. This behavior, not observed in other charge transfer oxides at low doping level, could result from the inhom ogeneous character of the doped system and from a Ni3d-O 2p hybridization enhancement due to the shortening of the relevant Ni-O distance in the localized hole-doped regions.

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I. IN TRODUCTION

Oxides of 3d transition m etals have attracted considerable attention in the last two decades because they exhibit very varied and fascinating properties (metalinsulator transition, high T c superconductivity, intricating magnetic properties). These behaviors partly result from an interplay of low dimensionality and electronic correlations. M any transition m etal oxides exhibit a two dimensional electronic structure. Due to its peculiar crystal structure, Y2B aN iO 5 is essentially a one dim ensional (1D) divalent nickel oxide. It crystallizes in a body-centered orthorhom bic structure within the Immm space group¹. The structure is characterized by linear chains of N iO 6 octahedra sharing corners along the z direction. The octahedra are compressed along the chains resulting in two short Ni-O distances (0.188 nm) and four longer N i-O distances $(0.219 \text{ nm})^1$. This unusual contraction and vanishing interactions between neighboring chains lead to a quasi-one-dimensional electronic structure². The hybridization between Ni-3d and 0-2p states is strong along the chain direction. Yet, Y_2B aN iO₅ has an insulating ground state due to exchange and correlation e ects. The superexchange antiferrom agnetic coupling between neighboring S=1 spins carried by N f^{+} ions in Y₂B aN iO 5 yields a quantum spin liquid ground state³. Large quantum spin uctuations associated with the 1D character of the NiO-Ninetwork

prevent the form ation of an ordered m agnetic state. The spin liquid can be described as m acroscopically coherent quantum state⁴ with a Haldane gap in the spin excitation spectrum ^{3,5}. Each S=1 spin can be considered as the triplet state form ed from the two ferror agnetically coupled S= 1/2 holes of N f⁺. Two S= 1/2 holes of neighboring sites form a singlet state. The ground state is then described in the well-known valence bond solid (VBS) picture. Excitations are triplet states obtained by breaking valence bonds. Hole doping in this spin liquid state results in interesting behaviors. Low energy spin excitations are characterized by incom m ensurate spin density m odulation around in purities, and the dynam ical spin structure factor reveals spectral weight in the Haldane gap^{5,6,7}.

>From an electronic point of view, Y_2B aN iO₅, like m ost of the N i and Cu oxides, belongs to the charge transfer regime in the Zaanen-Sawatzky-A llen diagram⁸. Then if the low-energy properties usually associated with spin excitations could be very di erent, the charge excitations and in particular the e ect of doping should look very similar in these families. The photoem ission spectrum of hom ogeneously hole doped system s on ly exhibits small spectral weight modi cations with doping whereas large spectral weight transfer is observed in the inverse photoem ission spectrum. In charge transfer oxides, a p symmetry is expected for the rst ionization states. Thus, the substitution of Sr or Ca divalent ions

for trivalent Y in $Y_2 \ _x Sr_x B$ aN iO 5 should yield holes in the ligand p band. Nevertheless, hybridization between N i-3d states and O -2p states can modify this picture by shifting highly hybridized $d^8 L$ states tow and the top of the 0 -2p band (L represents a hole on the ligand). As a consequence, the rst ionization states probed by photoem ission should have a 3d character. This spectroscopy, by measuring the electron-rem oval spectrum, can give information about the symmetry of the rst ionization states and about the modi cation of electronic properties in hole doped com pounds. The electronic structure of hole doped Y2B aN iO5 has been investigated with several methods including x-ray absorption spectroscopy (XAS)⁵, optical conductivity⁹, photoem ission and inverse photoem ission¹⁰. These experim ents show that doped holes have either 0 (2pz) orm ixed N $i3d_{3z^2}$ r^2 O $(2p_z)$ character. Hole doping introduces new empty localized states in the charge gap region without any spectral weight very close to the Ferm i level. The doped carriers are trapped in local bound states and should therefore locally distort the electronic structure only in the vicinity of their location giving rise to a possible non-hom ogeneous doping at the nanoscopic scale^{7,9}. Therefore, the system does not become metallic upon doping, and no charge ordering is observed.

In this paper, we investigate the electronic structure of $Y_2 \times Sr_x B aN$ iO 5 for x= 0, 0.1 and 0.2 by photoem ission spectroscopy. By using the photon energy dependence of the spectral density, we con m that the rst electron rem oval excitations have mainly a N i-3d character. M oreover, these m easurem ents illustrate the e ect of hole doping in this system by evidencing an increase in the spectral weight of d sym metry at the top of the valence band. In contrast to most of hole doped cuprates and nickelates which only present signi cant spectral modi cations for the unoccupied electronic states, a large spectral weight modi cation is observed in the photoem ission spectra of $Y_2 \ _x Sr_x B$ aN iO 5 for doping level as low as x=0.1. This singular behavior probably results from the large N i3d 0 2p hybridization along the chain direction and from the inhom ogeneous character of the doped system .

II. EXPERIMENTALDETAILS

Polycrystalline sam ples of $Y_2 \times Sr_x B$ an iO₅ (x=0.0, 0.10 and 0.20) were prepared by standard solid state reactions and characterized by X-ray powder di raction, m icroprobe and therm ogravim etric analysis. Sam ples are single-phased, hom ogeneously doped and stoichiom etric in oxygen¹¹. Photoem ission experiments have been carried out on the SU3 beam line of the French synchrotron facilities (LURE). The photon energy used was in the range extending from 60 eV to 200 eV. The sam ple surfaces were scraped in situ with a diam ond le to obtain clean surfaces under the ultrahigh vacuum of low 10⁻¹⁰ Torr. The clean liness of the surfaces was checked by the

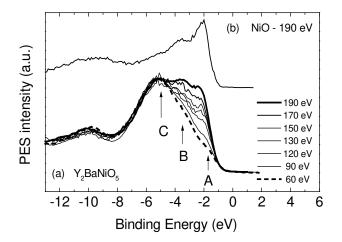


FIG. 1: (a)Angle-integrated photoem ission spectra of Y_2B aN iO₅ for several photon energies in the 60 eV -200 eV range. The spectra are arbitrary norm alized on them axim um of the C structure.(b) h = 190 eV - spectrum of N iO.

lack of contam inant in the valence band spectrum and by X-ray photoem ission core level spectra. The Ferm i energy was calibrated by m easuring the m etallic edge of a C u foil close to the sam ple. A llm easurem ents were carried out at room temperature with an energy resolution better than 50 m eV.

III. RESULTS AND DISCUSSION

In gure 1 we present angle-integrated photoem ission spectra of Y₂B aN iO₅ for photon energy varying between 60 eV and 200 eV. These spectra exhibit three features at Ε -2.0 eV,E -3.5 eV and E -5.0 eV , hereafter referred to as A, B and C, respectively. The peak at -10 eV, usually observed in Nioxides could originate from multielectronic e ects and/or in purity features¹². The spectra are arbitrarily norm alized on the C structure. W ith this normalization, a very strong photon energy dependence of the A feature intensity is clearly observed. Owing to the di erent photon energy dependence of d and p states cross section, this behavior suggests that the A feature is dom inated by the Ni-3d states whereas the B and C feature have likely p character. This result is in complete agreem ent with the previous m easurem ents carried out in the C a substituted oxide $(Y_2 \times C a_x B a N \text{ i} O_5)$ with H eI (h = 21.2 eV) and M g-K (h = 1253.6 eV) excitations¹² which exhibit the same trend. Moreover, spin polarized band calculations in the local density approximation conm this statement by showing that the C feature can be associated with 0 2p-N i3d bonding states with dom inant oxygen character whereas the states in the energy region of the B feature correspond to oxygen 2p-2p interactions with a non-bonding character with respect to

N i3d-0 2p interactions^{12,13}. A satisfactory agreem ent be-

tween band calculation and photoem ission spectra are

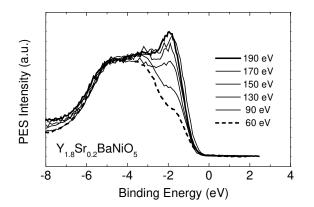


FIG. 2: Angle-integrated photoem ission spectra of $Y_{1:8} Sr_{0:2} B$ aN iO $_5$ for several photon energies in the 60 eV -200 eV range.

found for these two kinds of states^{12,13}. The top of the valence band in the calculations corresponds to antibonding states with a dom inant N i-3d contribution. Recent LSDA+U calculations, which predict a quite correct energy gap value, point out the highly hybridized character of these states¹³. A signi cant disagreem ent between band calculated density of states and photoemission spectrum are exhibited for these states. This is not surprising since the A structure represents excitations of correlated d states which are poorly described by one-electron (ground state) approaches. Such a valence spectrum is usually observed in divalent Ni oxides like N iO 14 , as observed in F ig.1 (b) where the photoem ission spectrum of N iO recorded with 190 eV photon-energy is presented. In N iO, the main structure close to -2eV has been interpreted to be due to $d^8 L$ states. The N i-3d derived structures are less resolved for Y₂B aN iO₅ than for N iO (at the sam e photon energy) because the transition metal to oxygen atom ic ratio is ve time larger in the Y_2B aN iO 5 compound. However, an increase in the absolute intensity of this feature can be evidenced by low ering the dimensionality in N iO (3D), La_2N iO₄ (2D) and $Y_2B = N iO_5 (1D)^{10}$.

A Itematively, transition m etaloxides can be described in many body approaches¹⁵. Y_2B aN iO₅ belongs to the charge transfer regime in the ZSA scheme because the charge transfer parameter () is smaller than the Coulomb term U^{10} . In this regime, the ligand p band is situated between the two Hubbard subbands. However, the photon energy dependence of the photoem ission spectrum clearly shows that Ni-3d symmetry dominates in the rst excited states of the photoem ission spectrum in contrast to naively expected in the charge transfer regime for which the rst electron rem oval excitations correspond to form ation of ligand holes in the p band. This behavior results from hybridization e ect. Indeed, as shown in the single impurity model¹⁵, the hybridization between Ni-3d and 0-2p leads to a modi cation of the simple picture of a 0-2p band between the lower and

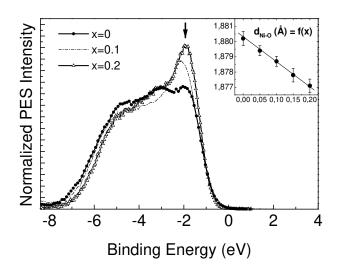


FIG. 3: Angle-integrated Photoem ission spectra for several doping after substraction of the Shirley background and normalized to the area (see explanation in the text). Insert: NiO distance as a function of doping x for Sr substituted samples. Data taken from Ref.¹¹

upper Hubbard bands. The led lower band will hybridize with the O-2p states inducing the appearance of an image Hubbard band at the low energy side of the p band^{15,16} (gure 4(a)). C luster calculation shows that the rst excitation state has a dom inant d⁸ \underline{L} character¹⁰ con-

m ing that the photoem ission hole is essentially on the ligand site. Such a behavior is usually encountered in divalent N ioxide like N iO 14. Figure 2 shows the sam e photon energy dependence for the doped $Y_{1:8}$ S r_{0:2} B aN iO 5 compound. This evolution shows that the spectral feature at low energy signi cantly increases in intensity with increasing photon energy con ming that this feature has a N i-3d character. C om parison with gure 1 shows that the main e ect of hole doping is to increase the intensity of feature A. Moreover, a narrowing of the bandwidth is also observed. In order to illustrate the increase in intensity, we report in gure 3 the photoem ission spectra of x=0.0, 0.1 and 0.2 oxides for h = 190 eV after substraction of the standard Shirley background. Note that this photon energy has been chosen in order to em phasize the doping e ect on the spectral density. Nevertheless, gure 1 and gure 2 show that this e ect is not energy dependent. The gure 3 illustrates the large e ect of hole doping on the photoem ission spectral weight in $Y_2 \times Sr_x B$ aN iO₅. First, the doping induced-states have negligible density of states near the Ferm i energy and do not yield the form ation of a metal. The photoem issionprobed part of the gap (400 m eV) seems indeed to be not a ected by doping. The present data and the optical conductivity of reference⁹, which evidences a gap of 0.3eV, con m that the Ferm i level is located immediately below the new unoccupied states induced by doping.

The absence of spectral weight at E $_{\rm F}\,$ is corroborated by resistivity m easurem ents which show that the doped

oxides remain insulating9. Secondly, even for low x, the A feature exhibits a very large increase in intensity with doping. This behavior contrasts to the usually observed spectral weight modi cation in hole doped divalent Nioxides, and more generally in cuprates and nickelates. In $La_2 xSr_xNiO_4$, for instance, no signi cant increase in the spectral weight intensity is observed for doping level smaller than $x=0.5^{17}$. Unfortunately, due to the relative content of 0-2p and Ni-3d states, it is not really possible to quantitatively estimate the weight of the $d^{8}L$ state. Transfers of spectral weight in hole-doped strongly correlated system s have been previously discussed in detail in the literature¹⁶. A nom alous spectral weight modi cations related to electronic correlations are expected in the electron-addition part (unoccupied states) of hybridized charge transfer system s. This trend is indeed observed in the XAS oxygen K edge of Y_{2 x} (Ca;Sr)_xBaN iO₅^{5,11} as well as in inverse photoem ission¹⁰. However the electron-rem oval part of the spectrum (occupied states) should slightly decrease upon doping within this approach (since some low energy states are depopulated) in contrast to the spectroscopic behavior. An additional mechanism has to be invoked to explain the evolution of photoem ission spectra with Sr content. Interestingly, hole doping in Y_2B aN iO 5 could result in an increase in the N i3d 0 2p hybridization since, unlike in $La_2 \times Sr_x N$ iO 4^{18} , the average N i-0 distance shortens continuously upon doping (see insert gure 3 for $Y_2 \times Sr_x B$ aN iO 5 and references 19,20 for $Y_2 \times Ca_x BaN iO_5$). As the apical N i-O distance in Y_2BaNiO_5 is the shortest one observed in nickelates, a small decrease should lead to a large increase in hybridization. This will be emphasized in case of an inhom ogeneous doping. If the doped holes are trapped in local bound states, disturbing the electronic states only in their vicinity^{7,9}, the real Ni+O bonds in these perturbated part of the sample should be shorter than the average one m easured by X -rays. As a consequence, in the photoem ission spectra, which are the simple addition of unperturbated parts and doped parts, the A peak enhancem ent should originatem ainly from the holedoped regions where the hybridization strongly increases. Therefore, the d character of the top of the valence band should be emphasized in the doped compounds due to this strong hybridization enhancement. A similar e ect is expected for C a doped m aterials and has been observed for highly doped samples in X-ray photoem ission¹² in spite of the poor energy resolution.

This scenario of a very large spectral weight modication due to doping-dependent hybridization is in qualitative agreement with the modi cation of the valence photoem ission spectra we observed with Sr content in $Y_2 \ _x S r_x B aN iO_5$. Figure 4 sum marizes the spectroscopic results obtained on hole doped $Y_2 \ _x S r_x B aN iO_5$. Firstly, we recall in Fig. 4(a) the elect of hybridization in the impurity approach used to describe qualitatively the spectroscopy of hom ogeneous charge transfer transition metal oxides¹⁵. Hybridized d⁸L states appear at

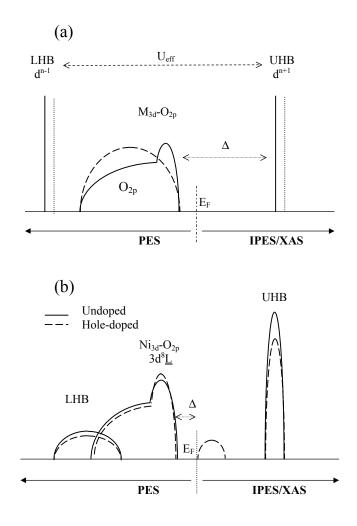


FIG.4: (a) E ect of hybridization on the spectral density of a non-doped charge-transfer oxide in the impurity approach. From Ref.¹⁵. (b)Schem atic view of the situation encountered in $Y_2 \ _x Sr_x B$ an iO₅. Hole doping leads to a large spectral weight transfer in the electron-addition part and m ore surprisingly to a spectral weight increase in the rst electron-rem oval states.

the top of the O -2p band. O byiously, the 3d character of these states increases with increasing N i3d-O 2p hybridization. Secondly, Fig.4 (b) illustrates the e ect of hole doping in Y_2B aN iO 5. In charge transfer systems, hole doping usually a ects the electron-addition spectra by the appearance of the spectral feature just above the Ferm i energy associated with the hole states. Hybridization, by introducing d character in these states, could enhance its spectral weight.

The singular behavior in doped Y_2B aN iO₅ is the increase in intensity of the rst ionisation states. This evolution, sim ilar to what is presented in Fig. 4(a), reet the increase in hybridization within the localized hole-doped regions. We note that a theoretical treatment, based on a multiband H am iltonian containing the

relevant N i and O orbitals, gives large values of transfer integrals within a hole-doped N iO₆ cluster²¹. This singular spectroscopic signature, only observed in doped Y_2B aN iO₅, could result from the particularly sm allN i-O distance characterizing this quasi-1D com pound.

IV. CONCLUSION

To sum m arize, we have perform ed an angle-integrated photoem ission investigation of the spectral weight m odi cation by hole doping in the Y_2 $_xSr_xB$ aN iO $_5$ oxides. In this Haldane chain compound, hole doping leads to strong m odi cations in the unoccupied part of the spectral density as usually observed in cuprates and nickelates. However, photoem ission spectroscopy exhibits a singular behavior since a signi cant spectral weight increase corresponding to nal states with d character is observed. We propose that this surprising behavior could result from an increase in hybridization between Ni-3d and O-2p states induced by the reduction of Ni-O distance in the chain direction by doping. Such an elect is favoured by the inhom ogeneous character of doping. We hope that reliable calculations will be performed in the future to understand this anom alous spectral weight enhancement.

V. ACKNOW LEDGEMENT

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